

## MEG II 実験液体キセノン検出器用MPPCに対して 低温環境が与える影響の評価

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#### Introduction

- The motivation of searching  $\mu \rightarrow e \gamma$
- Overview of MEG II
- Liquid xenon photon detector

#### **MPPC**

- VUV-sensitive MPPC
- The mechanism of VUV detection
- MPPC PDE decrease
- Surface damage by VUV light

#### **Measurement of PDE decrease**

- Motivation of the measurement
- Setup
- · Result
- Summary

### The motivation of searching $\mu \rightarrow e \gamma$

- Neutrino oscillation was discovered (1998)
  - →Shows that neutrinos have mass and mixing
- $\mu \rightarrow e \gamma$  in the standard model

$$Br(\mu \to e\gamma) = \frac{3\alpha}{32\pi} \left| \sum_{i=2,3} U_{\mu i}^* U_{ei} \frac{\Delta m_{i1}^2}{M_W^2} \right|^2 \simeq 10^{-54}$$

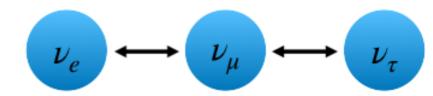
→Cannot be observed

- $\mu \rightarrow e \gamma$  in a new physics e.g. SUSY GUT
  - →Assume unknown heavy particle

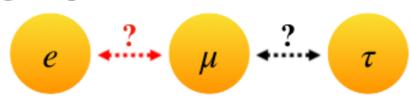
$$Br(\mu \to e\gamma) = \mathcal{O}(10^{-12}) - \mathcal{O}(10^{-14})$$

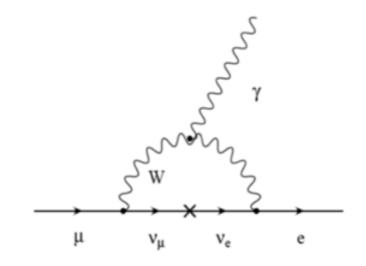
 $\rightarrow$ Can be observed

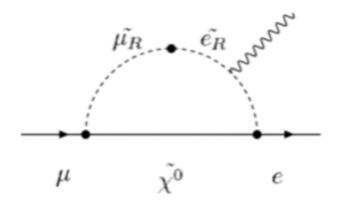
#### Neutrino



#### Charged lepton







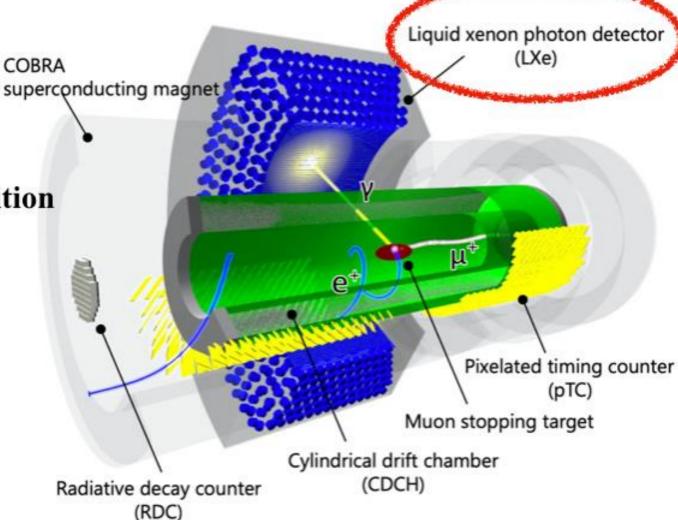
# Overview of the MEG II experiment at Paul Scherrer Institut



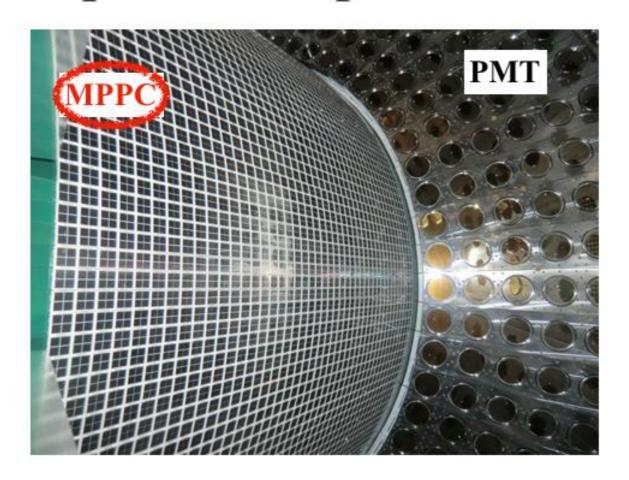
- The world's most intense  $\mu$  beam  $7 \times 10^7 \mu/\text{sec}$
- Muons are stopped at the target
- Two-body decay

 The photon energy, interaction point position and time are measured by <u>LXe</u>

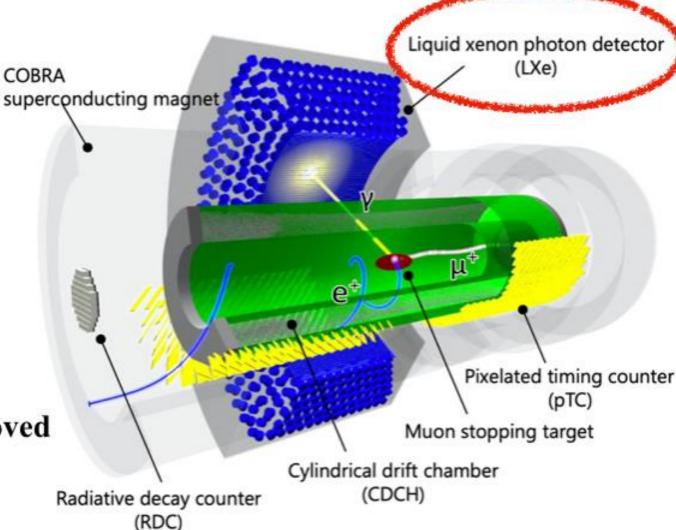




### Liquid xenon photon detector (LXe)



- · Liquid xenon to measure 52.8MeV photon
- Detect the scintillation ( $\lambda = 175$ nm)
- · 4092 MPPC , 668PMTs at 165K
- Energy and position resolutions will be improved as compared with MEG by a factor of two
- Under commissioning since 2017



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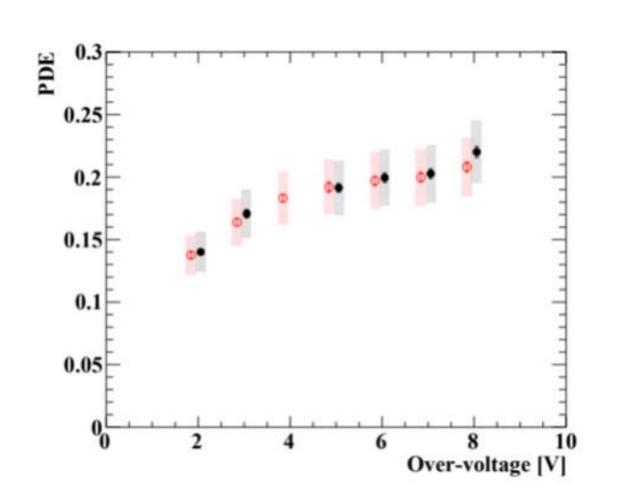
### **VUV-sensitive MPPC (SiPM)**

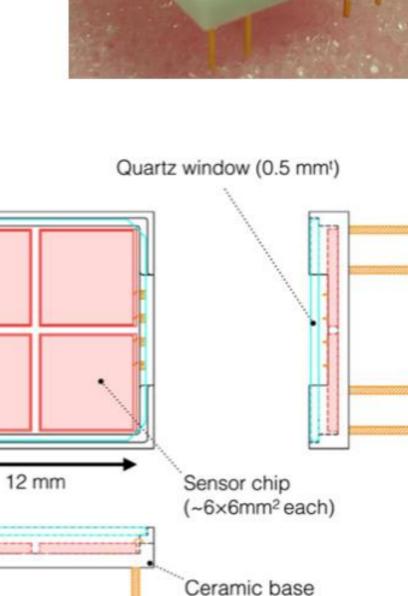
- · SiPM is a high-performance photon detector
- VUV-sensitive MPPC has been newly developed for MEG II

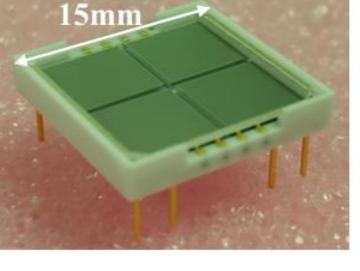
15 mm

2.5 mm

- Operational at low temperature (165K)
- Photon detection efficiency (PDE) >15% at  $\lambda = 175$ nm
- Large sensitive area  $(12 \times 12 \text{ mm}^2)$



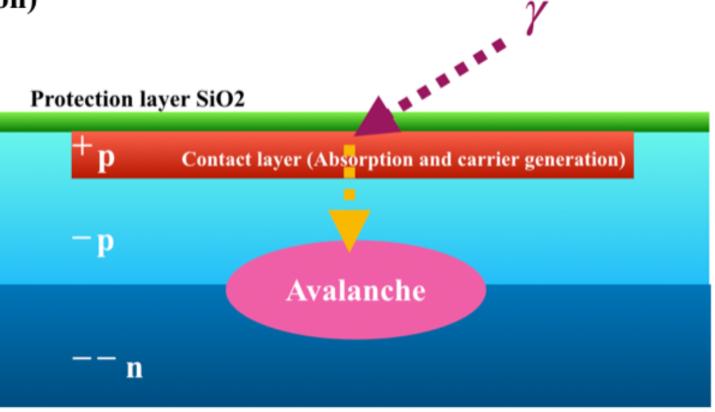




### The mechanism of photon detection

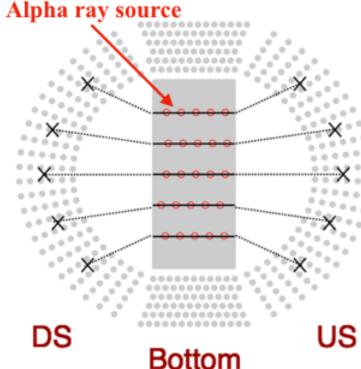
- General SiPM
- Depletion layer: p-n junction
- Incoming photons generate electron-hole pairs
- Reverse voltage is larger than a threshold
  - →"Geiger mode"
- · In geiger mode, carriers make other carriers
  - →Number of electron-hole pairs increase exponentially (avalanche multiplication) to make a signal
- Insensitive to VUV
  - →VUV stops near the surface
  - →Visible light reach the deep part

- VUV-sensitive MPPC
  - Remove the protection coating (epoxy)
  - · Thin down the contact layer



### **VUV-sensitive MPPC PDE decrease**





Normalized Response Response to LED light Response to VUV light 0.95 0.9 [hours at MEG II intensity] Exposure to muon beam 200 Accumulated Exposure 140 120

MPPC Response under muon beam

cf. 16pG22-11(Satoru),16pG22-12(Kei),16pG22-13(Shinji)

- Alpha ray sources are in the detector
  - → Produce VUV scintillation light

• PDE = 
$$\frac{\text{N(photon)}_{\text{observed}}}{\text{N(photon)}_{\text{expected}}} \sim 8\%$$

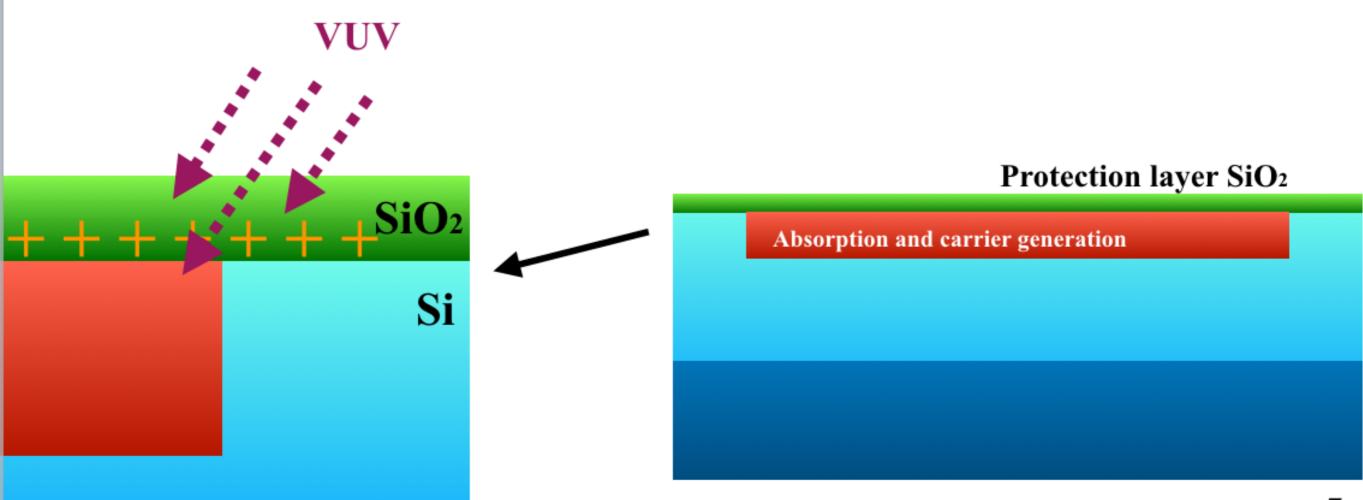
 $\rightarrow$ much lower than that measured in Lab(>15%)

- Degradation of MPPC VUV-sensitivity
  - $\rightarrow$ quite fast ~0.05%/hour (under MEG II beam intensity  $7 \times 10^7 \mu/\text{sec}$ )
- · MEG II DAQ time (design): 140 days/year, 3 years
  - →This degradation is not negligible
- · A possible cause: Gamma, Neutron irradiation
  - →In lab test, no effect on PDE was observed (at room-temp)

+

### Surface damage by VUV light

- Electron-holes are generated in SiO2 by VUV light
- Holes are trapped at interface SiO<sub>2</sub>-Si
- The electric field near the boundary of the two surfaces will be reduced by the holes
  - →Collection efficiency will be reduced
- Degradation seems accelerated at low temperature
  - →Holes hardly move



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#### Motivation of the measurement

cf. 17aG22-7(Rina)

PDE degradation of the MPPC was observed in LXe photon detector

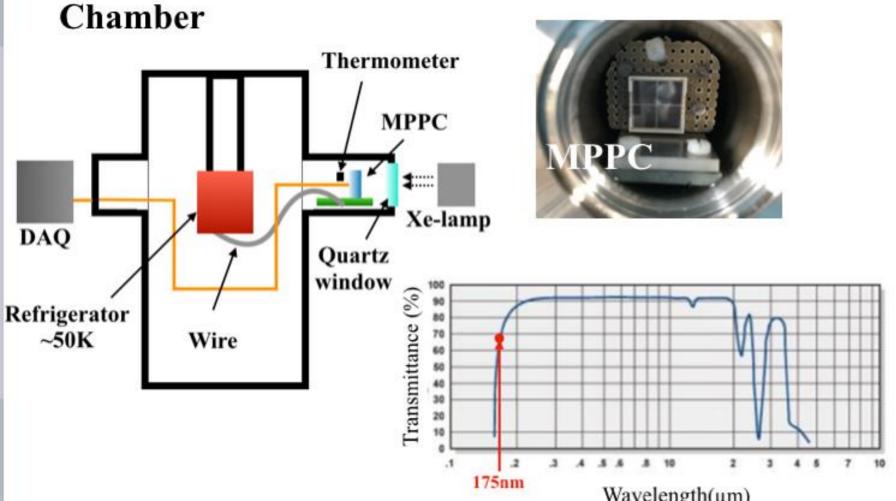
- · PDE decrease by VUV irradiation at room-temp was slower than in LXe photon detector
- Gamma, Neutron irradiation has no effect on PDE in previous research at room-temp (Cannot exclude the possibility that the irradiation damage(Gamma, Neutron) at low-temp is different from room-temp)
- To survey the effect of low temperature on the PDE decrease
  - →Compare the PDE decrease at room temperature and low temperature
- To induce and monitor the PDE decrease
  - →Irradiate a MPPC
  - →Read current with no bias voltage (Gain 1)

    (in previous research, correlation between current and PDE was observed)

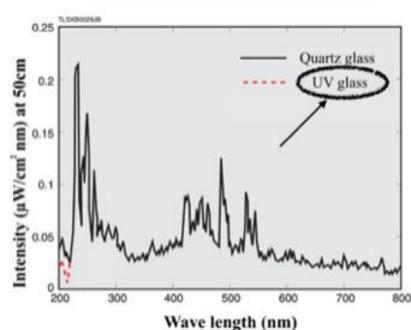
### Setup

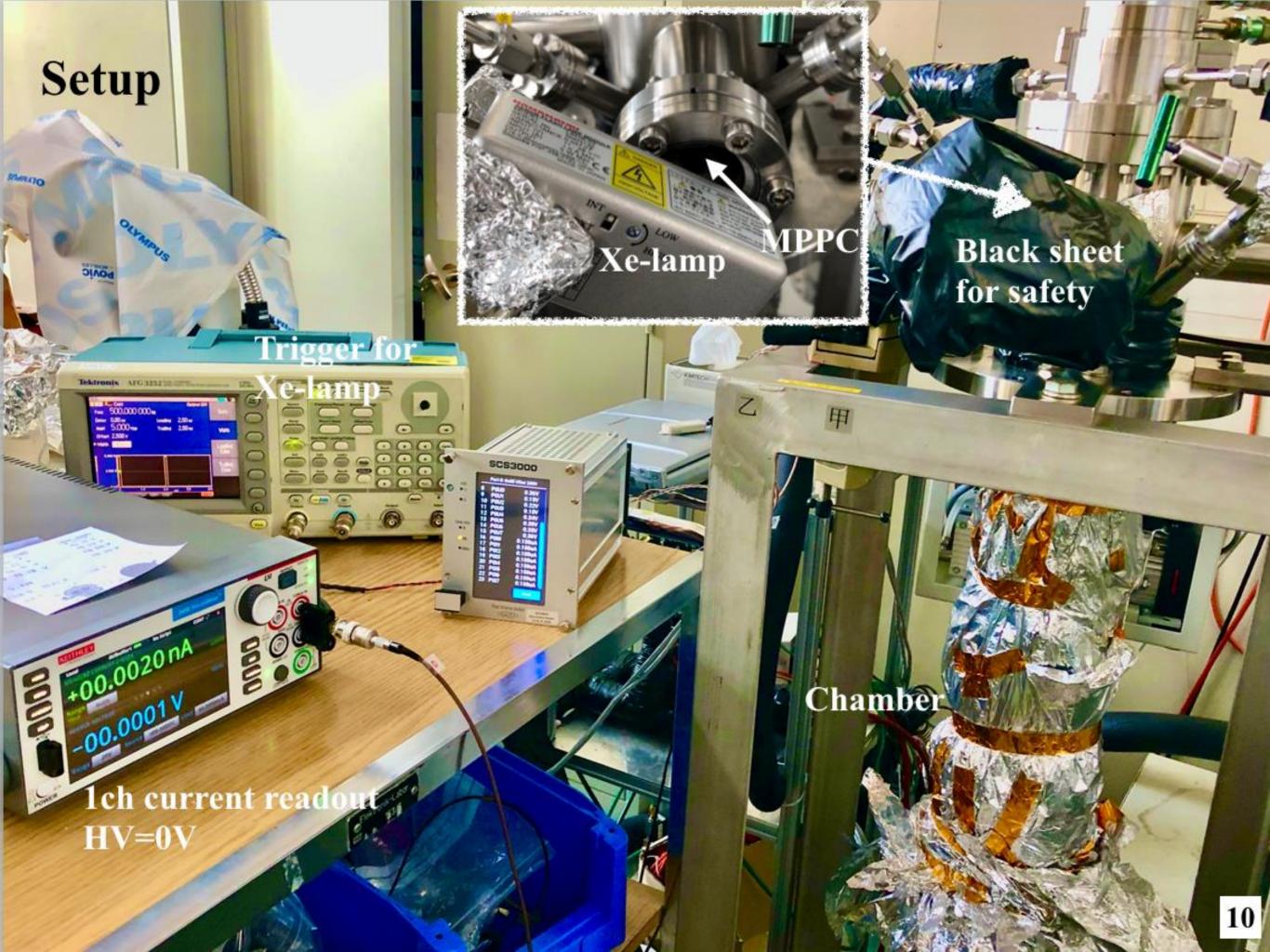
- Make vacuum in the chamber for insulation
- Wire carries low temperature from refrigerator
- · ~240K, around the MPPC
  - →Could not reach the LXe temp(165K)

- · MPPC is irradiated through quartz window
  - →Distance : 5cm
- Read 1chip current (MPPC has 4chip)
  - $\rightarrow$ HV=0V
- · Xe flash lamp as a irradiation source
  - →To irradiate with short-wavelength light (~175nm)

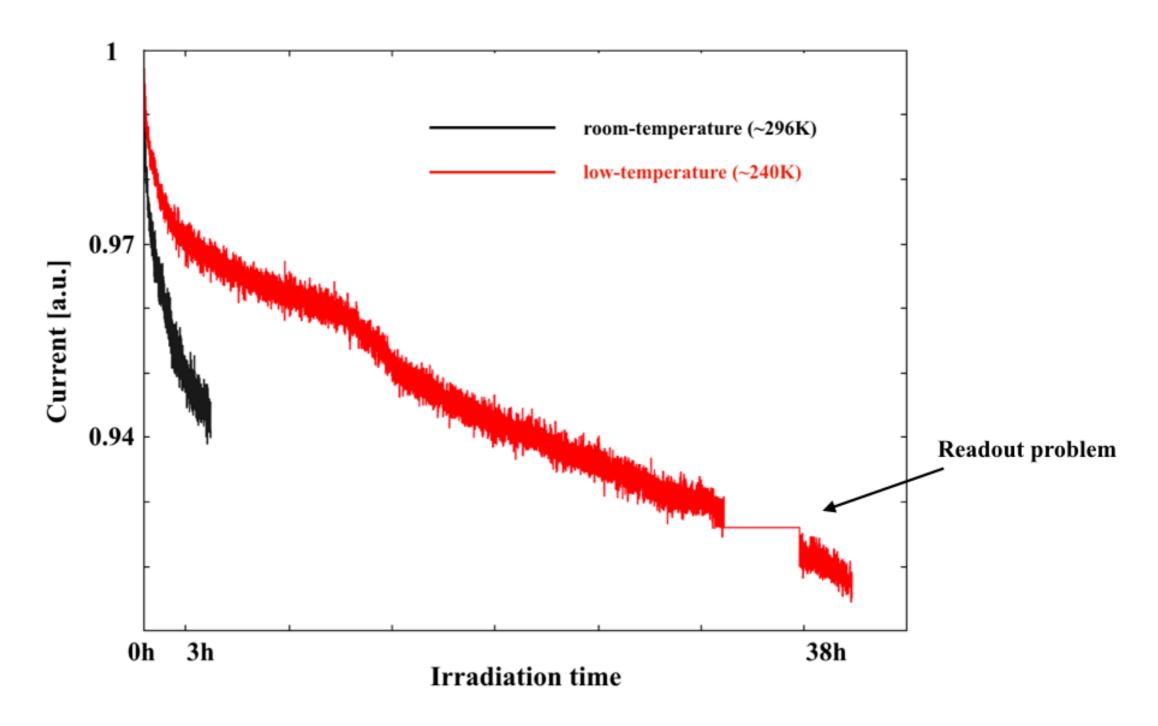






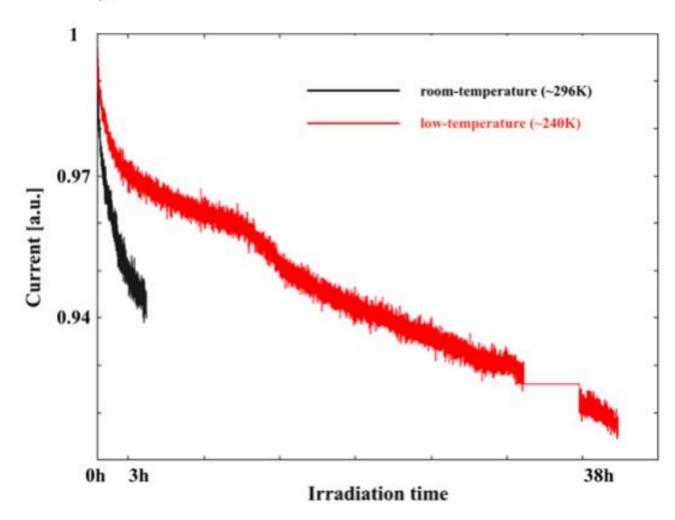


### Result (HV=0V)



• Irradiated one MPPC (low-temp  $\rightarrow$  room-temp)

### Result (HV=0V)



- Decrease of current was observed both at low-temp and room-temp
  - →This might show PDE decrease
- The decrease level of low-temperature is smaller than room-temperature
  - →Contrary to expectation
- The result includes the entire wavelength region
  - →Different from VUV irradiation
- The temp (~240K) is much higher than LXe temp (165K)

### Summary

#### Measurement

Room temp(~296K) vs Low temp(~240K)

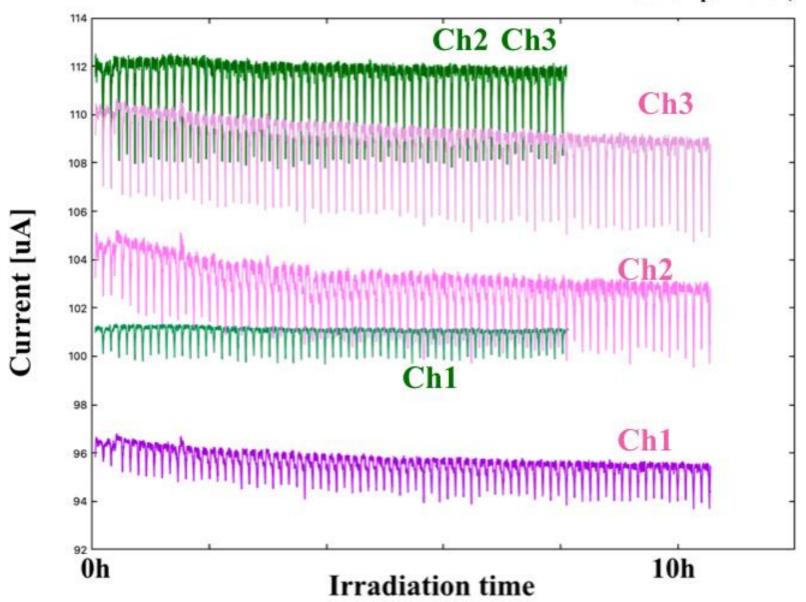
- Could not reach the <u>LXe</u> temp(165K)
  - →Improve the setup (replace the wire with copper one and improve the insulating performance)
- · Contrary to expectations, current decrease at low temp was slower
  - →We do not know the reason
  - →The possibility that we did not measure the PDE decrease for VUV light (Xe-lamp includes other wave length)
  - →We should measure the charge for VUV light using filters

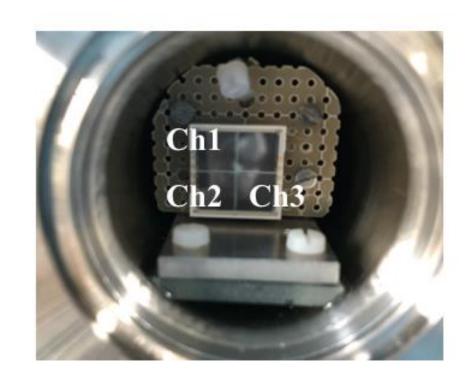
## Backup slides

Result (HV=4V)

room-temperature (296K)

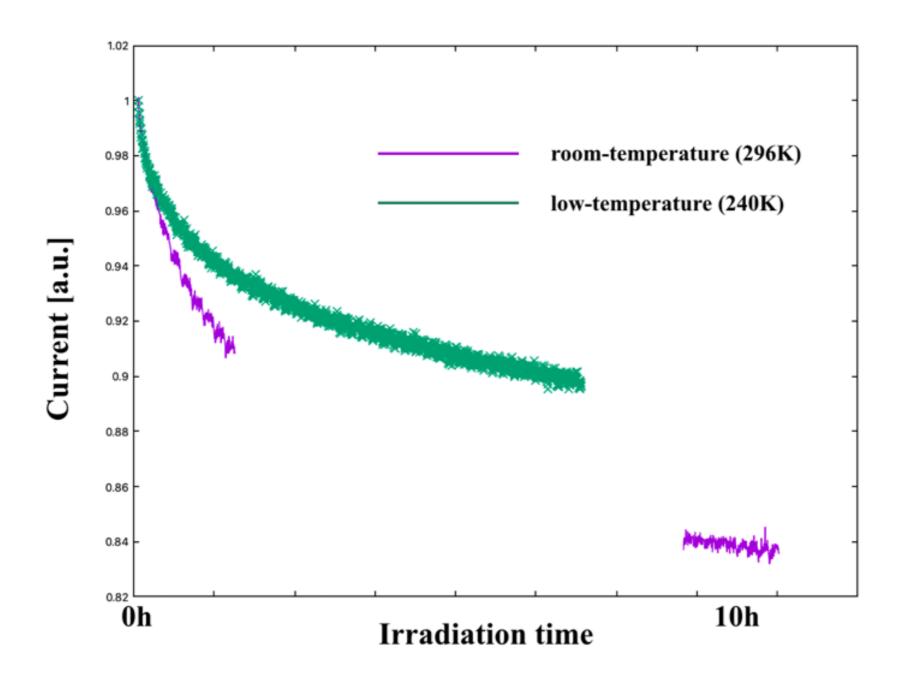
low-temperature (240K)





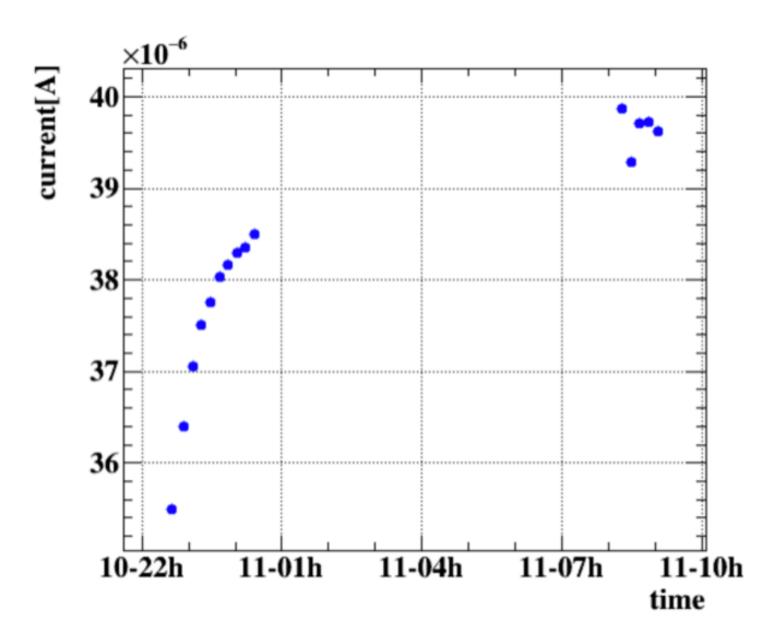
- · Total irradiation time: ~10h
- · When bias voltage are supplied, low-temperature current seems to decrease
- · The result is opposite to that w/o HV

### Result (HV=0V)



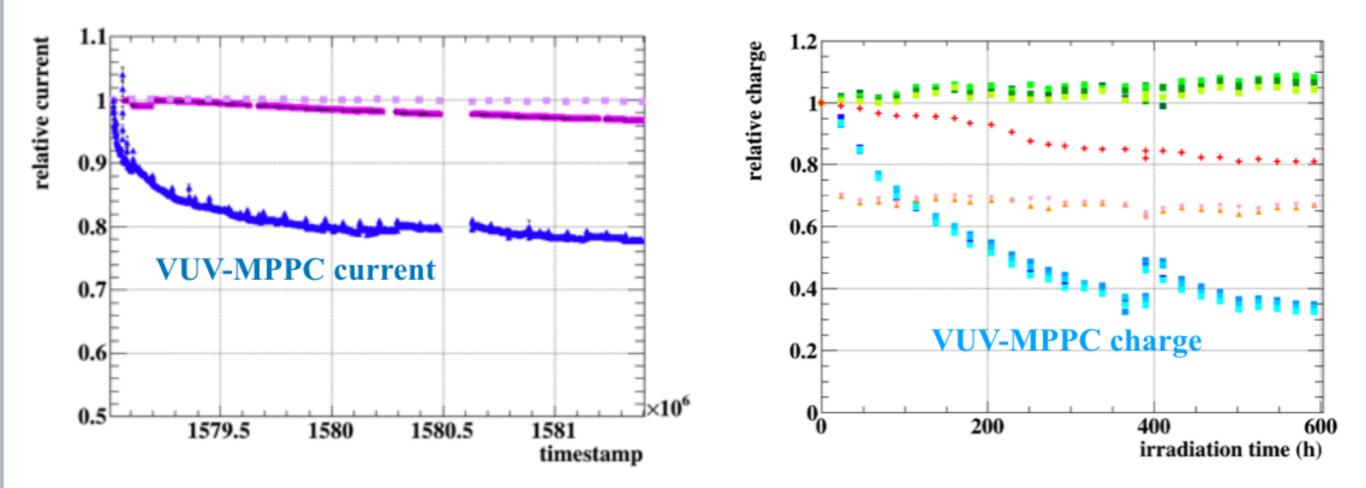
- · Irradiated two MPPCs
- Consistent with the result using one MPPC

### LED response



- MPPC Vover~6V
- Xe lamp off
- current(LEDon) current(LEDoff)
   to remove the dark current

- Increase of the response to the LED was observed
- · Possibly, there happened to be UV cleaning



 Correlation between current decrease and charge decrease was observed in previous measurement